

N-channel 60 V, 3.9 mΩ standard level MOSFET in SOT78 1 February 2013 Product data sheet

1. General description

Standard level N-channel MOSFET in SOT78 using TrenchMOS technology. Product design and manufacture has been optimized for use in battery operated power tools.

2. Features and benefits

- High efficiency due to low switching & conduction losses
- Robust construction for demanding applications
- Standard level gate

3. Applications

- Battery-powered tools
- Load switching
- Motor control
- Uninterruptible power supplies

4. Quick reference data

Table 1. Qui	ick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	60	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	-	130	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	263	W
Static charact	teristics						,
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11		-	2.94	3.9	mΩ
Dynamic chai	acteristics	·					
Q _{G(tot)}	total gate charge	I_D = 25 A; V_{DS} = 48 V; V_{GS} = 10 V;		-	103	-	nC
Q _{GD}	gate-drain charge	<u>Fig. 13; Fig. 14</u>		-	33	-	nC
Avalanche rug	ggedness				1		
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 130 A; $V_{sup} \le 60$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; Fig. 3		-	-	283	mJ

[1] Continuous current is limited by package.

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain	$2 \sim 10$	
3	S	source		G L F A
mb	D	mounting base; connected to drain		mbb076 S
			TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PSMN3R9-60PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN3R9-60PS	PSMN3R9-60PS

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

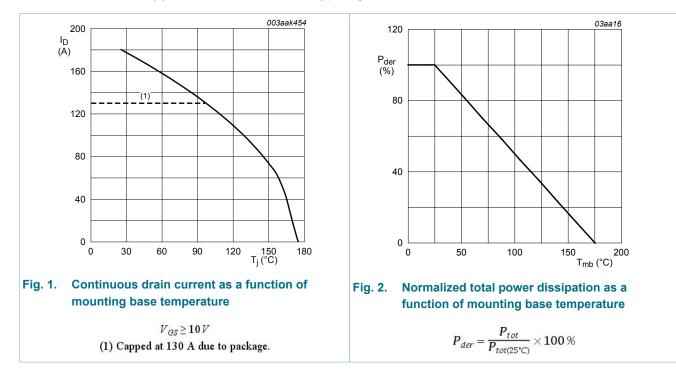
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}$		-	60	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	130	А
		T _{mb} = 100 °C; V _{GS} = 10 V; <u>Fig. 1</u>		-	127	А
I _{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \le 10 \ \mu$ s; Fig. 4		-	705	А

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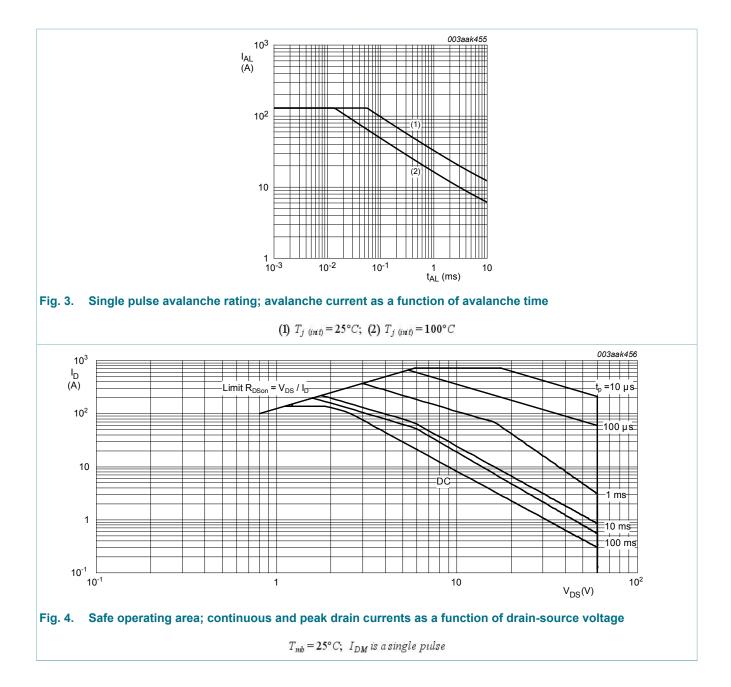
Symbol	Parameter	Conditions		Min	Мах	Unit
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	263	W
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drai	in diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	130	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	705	А
Avalanche	ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\begin{split} & I_{D} = 130 \; A; V_{sup} \leq 60 \; V; R_{GS} = 50 \; \Omega; \\ & V_{GS} = 10 \; V; T_{j(init)} = 25 \; ^{\circ}C; \; unclamped; \\ & \overline{Fig. 3} \end{split}$		-	283	mJ



[1] Continuous current is limited by package.

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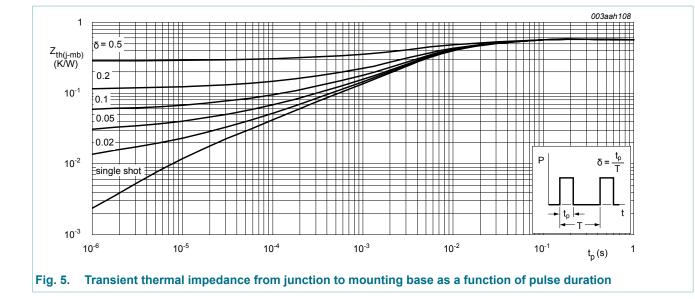
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9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	0.49	0.57	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	vertical in still air	-	60	-	K/W

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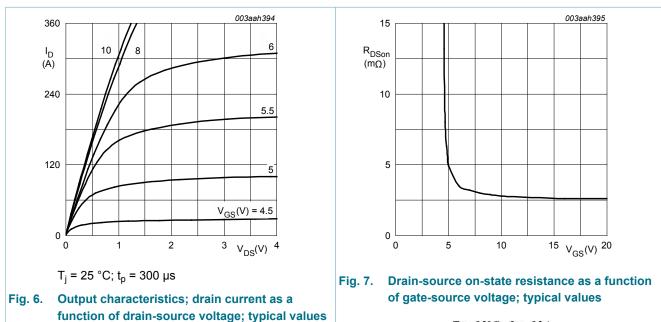
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V
	breakdown voltage	$I_D = 250 \ \mu A; V_{GS} = 0 \ V; T_j = -55 \ ^{\circ}C$	54	-	-	V
V _{GS(th)}	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 9; Fig. 10	2.4	3	4	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 175 °C; Fig. 9	1	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = -55 °C; Fig. 9	-	-	4.5	V
I _{DSS}	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA
		V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	0.07	1	μA
I _{GSS}	s gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11	-	2.94	3.9	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 11; Fig. 12	-	-	8.5	mΩ
R _G	gate resistance	f = 1 MHz	0.35	0.7	1.4	Ω
Dynamic cl	naracteristics		I			
Q _{G(tot)}	total gate charge	I_D = 25 A; V_{DS} = 48 V; V_{GS} = 10 V;	-	103	-	nC
Q _{GS}	gate-source charge	<u>Fig. 13; Fig. 14</u>	-	25.1	-	nC

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GD}	gate-drain charge			-	33	-	nC
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz;		-	5600	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>		-	740	-	pF
C _{rss}	reverse transfer capacitance			-	460	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 45 V; R _L = 1.8 Ω; V _{GS} = 10 V; R _{G(ext)} = 5 Ω		-	25.3	-	ns
t _r	rise time			-	41.4	-	ns
t _{d(off)}	turn-off delay time			-	62.7	-	ns
t _f	fall time	-		-	45	-	ns
Source-dra	ain diode	l	1				
V _{SD}	source-drain voltage	I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u>		-	0.8	1.2	V
t _{rr}	reverse recovery time	$\rm I_S$ = 20 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; $\rm V_{DS}$ = 25 V		-	39	-	ns
Qr	recovered charge			-	51	-	nC

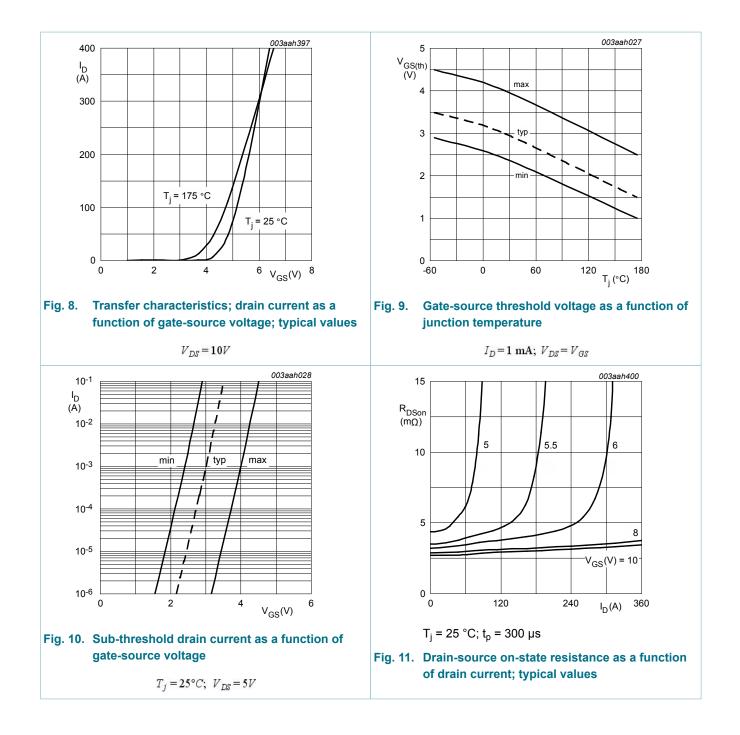


 $T_j = 25^{\circ}C; \ I_D = 25A$

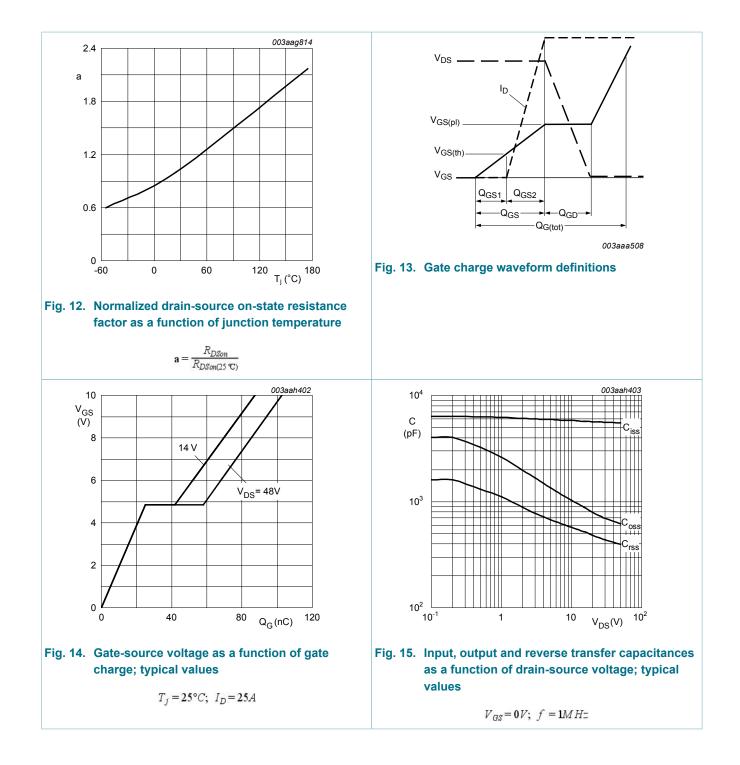
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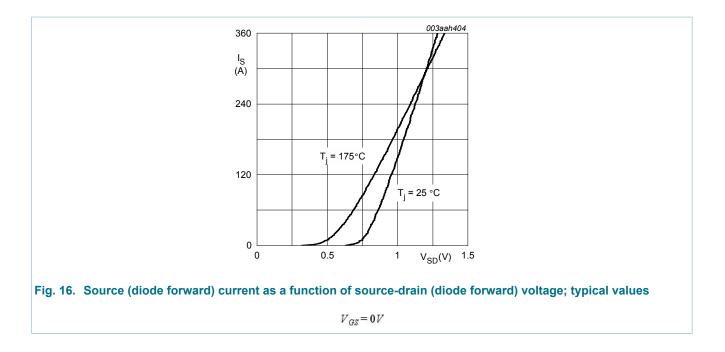


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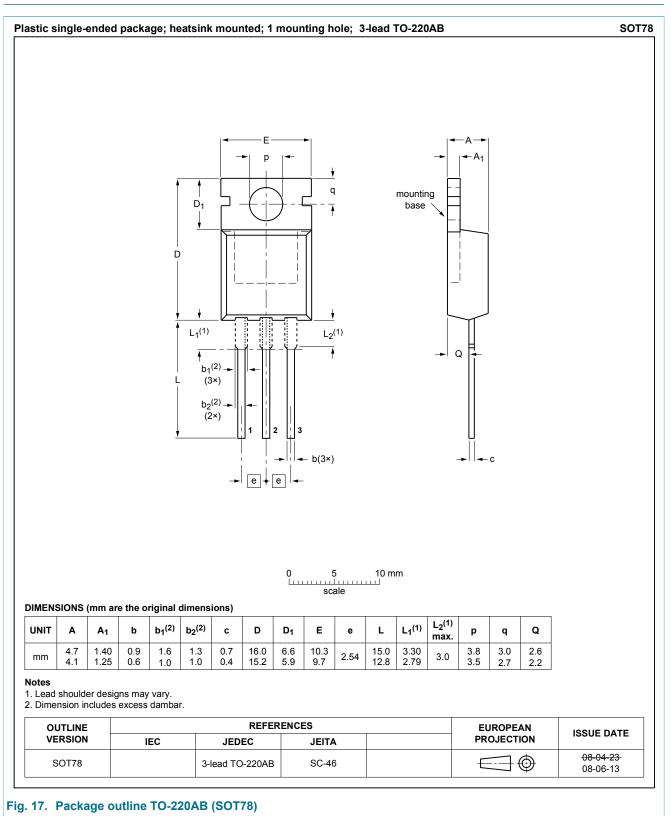
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11. Package outline



PSMN3R9-60PS

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12. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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